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PLASMON DAMPING IN GRAPHENE

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Outline

- Problem and motivation
- Relaxation time approximation figure of merit: $\Gamma = \frac{1}{\tau}$

Optical conductivity:
 Experiment
 Theory (damping channels)

- Experiments: plasmon dispersion and linewidth
- Conclusion
- P.S. Near field heat transfer & thermo-photovoltaics using graphene's plasmons

Problem and motivation

- Plasmonics surface plasmons
- Exciting technological applications
 - Metamaterials
 - Nonlinear phenomena SERS
 - Merging electronics and photonics
- Subwavelength: $\lambda_{sp} << \lambda_{air}$
- Trade-off: small propagation lengths
- Plasmons in graphene
- Plasmon damping?
- Jablan et al., PRB 80, 245435



Random phase approximation



• Plasmon dispersion:
$$\varepsilon(\vec{q},\omega) = 0$$

- Plasmon damping: $\operatorname{Im} \mathcal{E}(\vec{q}, \omega) > 0$
- Landau damping







Relaxation time approximation

• Damping channels (outside of Landau damping region)

impurites, defects, edges
 phonons (acoustical, optical, surface polar)
 e-e correlation beyond RPA

phenomenological relaxation time $\,\mathcal{T}\,$



Relaxation time approximation:

$$\frac{d\rho}{dt} = \frac{1}{i\hbar} [H,\rho] - \frac{1}{\tau} (\rho - \rho_0)$$

• Mermin, Phys. Rev. B 1, 2362 (1970)

• Figure of merit:

$$\Gamma = \frac{1}{\tau} \quad \left[\mathrm{cm}^{-1} \right]$$

• Drude model:
$$\sigma(\omega) = \frac{e^2 E_F}{\pi \hbar^2} \frac{i}{\omega + i \cdot \Gamma}$$
 $\omega \to \omega + i \cdot \Gamma$

DC scattering rate

- DC scattering rate: $\Gamma_{\! DC} \propto \mu^{-1}$
- Typical measured values:



• How good is this Γ_{DC} approximation?

Optical phonon scattering

• Optical phonon: $\Omega_{OP} = 200 \text{ meV}$



• Room temperature DC measurements:

 $kT \approx 25 \text{ meV}$

• Plasmon energy: $\hbar\omega_{_{pl}} > \hbar\Omega_{_{OP}}$





Optical phonon scattering

• Optical phonon: $\Omega_{OP} = 200 \text{ meV}$



- Room temperature DC measurements:
 - $kT \approx 25 \text{ meV}$
- Plasmon energy: $\hbar\omega_{_{pl}} > \hbar\Omega_{_{OP}}$





• Jablan et al., PRB 80, 245435

Conductivity

- Losses: $\operatorname{Im} \varepsilon(\vec{q}, \omega) \propto \operatorname{Re} \sigma(\vec{q}, \omega)$
- Case: q = 0
- Optical experiment (normal incidence light scattering)
- Typical conductivity profile







Nair et al.,
 Science 320,
 1308 (2008)

Conductivity (experiment)

Interband Threshold

1.0 0.8 $\sigma_1(\pi e^2/2h)$ 0.6 0.4 0.2 Plateau 0 5,000 6,000 7,000 1,000 2,000 3,000 4,000 8.000 0 ω (cm-1)

• Li et al., Nature Phys. 4, 532 (2008)

 $\Gamma(2000 \,\mathrm{cm}^{-1}) \approx 400 \,\mathrm{cm}^{-1}$



 $\Gamma_{DC} = 30 \,\mathrm{cm}^{-1}$

Optical phonon

• Phonon scattering

$$\sim$$

- Electron self-energy:
- Optical phonon:
 - $\Omega_{OP} = 200 \text{ meV} = 1600 \text{ cm}^{-1}$



• Acoustical phonon – negligible



• Stauber et el. PRB 78, 085418 (2008)

Surface polar phonon



- Surface polar phonon (SiO₂):
- $\Omega_{SP1} = 59 \text{ meV} = 470 \text{ cm}^{-1}$

$$\Omega_{SP2} = 156 \text{ meV} = 1260 \text{ cm}^{-1}$$



• Scharf et el. PRB 87, 035414 (2013)

e-e correlation

• Screened Coulomb interaction

• Electron self energy:



• Carbotte el. PRB 85, 201411 (2012)





Conductivity

1.0 Eŧ 0.8 $\sigma_1(\pi e^2/2h)$ 0.6 0.4 0.2 Plateau 0 7,000 1,000 2,000 3,000 4,000 5,000 6,000 8.000 ω (cm-1)

- Li et al., Nature Phys. 4, 532 (2008)
- Experiment ↔ Theory
- Quantitative difference
 (plateau hight interband threshold)
- Qualitative difference (doping dependence)

• Theory



- Scharf et el. PRB 87, 035414 (2013)
- Impurity (charged) scattering
- Phonon scattering:
 - Optical phonon
 - Surface polar phonon
 - Acoustical phonon (small)
- e-e correlation (small)

• Experiment

Plasmons in far IR

- Plasmon excitation
- Patterned graphene: breaking translation symmetry
- Micron size
- Far IR (THz) regime: $v = 5 \text{ THz} \approx 170 \text{ cm}^{-1}$ $(\lambda_{air} = 60 \ \mu\text{m})$





a 50

- Linewidth: $|\Gamma \approx \Gamma_{DC} = 120 \, \mathrm{cm}^{-1}$
- Ju et al., Nature Nanotech. 6, 630 (2011) Yan et el., Nature Nanotech. 7, 330 (2012)

 $\tau_{DC} \approx 100 \, \mathrm{fs}$

• Linewidth:
$$|\Gamma pprox \Gamma_{DC} = 50 \, \mathrm{cm}^{-1}$$

$$\tau_{DC} \approx 45 \, \mathrm{fs}$$

Plasmons in mid IR

- Mid IR : $v = 50 \,\mathrm{THz} \approx 1700 \,\mathrm{cm}^{-1} \,(\lambda_{air} = 6 \,\mu\mathrm{m})$
- Ribbon size: $W \approx 100 \text{ nm}$
- DLC substrate



• Yan et al., arXiv:1209.1984



Mid IR

• Fixed ribbon width W = 100 nm



- Yan et al., arXiv:1209.1984
- SiO₂ substrate



• DC scattering $\Gamma_{UNI} = 70 \, \mathrm{cm}^{-1}$

Mid IR

- Plasmon linewidth
- Plasmon momentum: $q \approx \frac{\pi}{100 \text{ nm}}$
- Yan et al., arXiv:1209.1984



• DC scattering: $\Gamma_{HOM} = 69 \text{ cm}^{-1}$

- Optical experiment
- Photon momentum: q = 0
- Li et al., Nature Phys. 4, 532 (2008)



• DC scattering: $\Gamma_{DC} = 30 \text{ cm}^{-1}$

Optical phonon scattering?

- Plasmon linewidth
- Plasmon momentum: $q \approx \frac{\pi}{100 \text{ nm}}$
- Yan et al., arXiv:1209.1984



• DC scattering: $\Gamma_{HOM} = 69 \text{ cm}^{-1}$

- Optical conductivity
- Stauber et el. PRB 78, 085418 (2008)



- Phonon scattering rate
- Jablan et al., PRB 80, 245435



Nanoscopy

• Optical nanoimaging





• Fei et al., Nature 487, 82 (2012)







Nanoscopy



EELS



- Tegenkamp et al., JPCM 23, 012001 (2011)
- Liu et al., PRB 78, 201403 (2008) $\Gamma = 10.6 \frac{v_F}{\lambda_{pl}}$

EELS



• Tegenkamp et al., JPCM 23, 012001 (2011) • Li et al., Nature Phys. 4, 532 (2008)

$$\Gamma = 3.8 \frac{v_F}{\lambda_{pl}}$$

$$\Gamma = \Gamma_{DC} + \left(2.5 \frac{v_F}{\lambda_{pl}}\right) \qquad \qquad \lambda_{pl} \propto \frac{E_F}{\omega^2}$$

• Plateau (doping independent)

Conclusion

- Plasmon linewidth
- Far IR: $\Gamma \approx \Gamma_{DC} > Optical$ (Micro-ribbons)
- Mid IR & Near IR: Γ >> Γ_{DC}
 ✓ Optical (Uniform)
 ➢ Optical (Nano-ribbons)
 ➢ Nanoscopy
 ➢ EELS
- Optical conductivity
 Experiment
 Theory

Near field heat transfer



• O. Ilic, M. Jablan, J.D. Joannopoulos, I. Celanovic, H. Buljan, M. Soljacic, Phys. Rev. B 85, 155422 (2012).

Thermo-photo-voltaics



• O. Ilic, M. Jablan, J.D. Joannopoulos, I. Celanovic, M. Soljacic, Optics Express 20, A366 (2012).

Thank you for your attention!